



## NRC Publications Archive Archives des publications du CNRC

### **Two-color control of localization: from lattices to spin systems**

Karczmarek, Joanna; Stott, Malcolm; Ivanov, Misha

This publication could be one of several versions: author's original, accepted manuscript or the publisher's version. / La version de cette publication peut être l'une des suivantes : la version prépublication de l'auteur, la version acceptée du manuscrit ou la version de l'éditeur.

For the publisher's version, please access the DOI link below. / Pour consulter la version de l'éditeur, utilisez le lien DOI ci-dessous.

#### **Publisher's version / Version de l'éditeur:**

<https://doi.org/10.1103/PhysRevA.60.R4225>

*Physical Review A*, 60, 6, pp. R4225-R4228, 1999-12-01

#### **NRC Publications Record / Notice d'Archives des publications de CNRC:**

<https://nrc-publications.canada.ca/eng/view/object/?id=8b3c3472-7d24-46d0-8b95-092ea158d064>

<https://publications-cnrc.canada.ca/fra/voir/objet/?id=8b3c3472-7d24-46d0-8b95-092ea158d064>

Access and use of this website and the material on it are subject to the Terms and Conditions set forth at

<https://nrc-publications.canada.ca/eng/copyright>

READ THESE TERMS AND CONDITIONS CAREFULLY BEFORE USING THIS WEBSITE.

L'accès à ce site Web et l'utilisation de son contenu sont assujettis aux conditions présentées dans le site

<https://publications-cnrc.canada.ca/fra/droits>

LISEZ CES CONDITIONS ATTENTIVEMENT AVANT D'UTILISER CE SITE WEB.

**Questions?** Contact the NRC Publications Archive team at

PublicationsArchive-ArchivesPublications@nrc-cnrc.gc.ca. If you wish to email the authors directly, please see the first page of the publication for their contact information.

**Vous avez des questions?** Nous pouvons vous aider. Pour communiquer directement avec un auteur, consultez la première page de la revue dans laquelle son article a été publié afin de trouver ses coordonnées. Si vous n'arrivez pas à les repérer, communiquez avec nous à PublicationsArchive-ArchivesPublications@nrc-cnrc.gc.ca.



## Two-color control of localization: From lattices to spin systems

Joanna Karczmarek,<sup>1,2</sup> Malcolm Stott,<sup>2</sup> and Misha Ivanov<sup>1</sup>

<sup>1</sup>*Steacie Institute for Molecular Science, NRC, 100 Sussex Drive, Ottawa, Ontario, Canada K1A 0R6*

<sup>2</sup>*Physics Department, Queen's University, Kingston, Ontario, Canada K7L 3N6*

(Received 13 July 1999)

We demonstrate control of quantum dynamics in a finite model system described by a tight-binding Hamiltonian, through interaction with a multifrequency external field. Effective defects can be introduced into the lattice by a two-frequency field, and the character of the defects can be controlled by the relative phase between the two field components. These field-induced defects imply robust localization of dressed (Floquet) states on lattice sites. Implications for a spin system in crossed magnetic fields are discussed. [S1050-2947(99)51211-0]

PACS number(s): 42.50.Hz

The desire to control dynamics of a quantum system is both a driving force and a unifying theme in many areas of modern laser-matter interaction physics. For example, atom optics focuses on controlling the translational degrees of freedom of an atom. Molecular optics [1] strives to extend this ability to molecules. Coherent control [2] focuses on using laser fields to manipulate the internal dynamics of atomic and molecular systems; e.g., creating complex superpositions of quantum states according to a given prescription [3].

Following the experiment [4], coherent control in solid-state systems became an active area [5]. In quantum-well semiconductor structures, one of the objectives is the control of electron motion between quantum wells. An intriguing theoretical prediction is the coherent suppression of electron tunneling between the wells [6] by application of a strong monochromatic THz electric field. Following the first experiments in quantum-well structures [7], this idea has been transplanted back into the quantum-optics context: narrowing of Bloch bands has been observed for cold neutral atoms in optical lattices [8], with ac driving due to phase modulation of the counterpropagating waves that create the lattice.

Suppression of tunneling is caused by a destructive interference of different multiphoton quantum pathways, and has far reaching consequences in the case of the tight-binding lattice. For example, manipulation of the strength of the THz field allows control of the effective strength of the existing defects in the lattice, the Anderson localization length, and consequently affects the temperature dependence of electron transport [9].

We have studied numerically and analytically coherent control of quantum dynamics in a tight-binding model system subject to a multifrequency periodic external field, extending the monochromatic field study [9]. Although our analytical results apply to any periodic field, we focus on the simple case of only two frequencies  $\omega$  and  $2\omega$ , where already we find a wealth of new effects.

First, unlike the single-frequency case, in a two-frequency field a delocalized initial state can be localized adiabatically at a single well, because the Floquet states of the driven system can be so localized. Second, the site where the electron is localized may be changed by adjusting the relative phase of the two frequencies. Third, compared to its single-frequency counterpart, the two-frequency localization is

stronger, and robust with respect to small changes in the external field strength. The two-frequency field introduces effective defects into the lattice, the strength of which depends on the relative phase of the two colors. For equal couplings between the sites the defects are induced at the ends of the lattice, but for couplings that are not all equal the defects are also induced within the lattice. In the presence of decoherence, the two-frequency driving can induce a tunneling current, whose direction is controlled by the relative phase between the frequencies.

The Hamiltonian for the tight-binding system together with an external time-dependent field is

$$\begin{aligned}\hat{H} &= \hat{H}_0 + V(t)\hat{N} \\ &= \sum_1^{N-1} \Omega_n(|n\rangle\langle n+1| + |n+1\rangle\langle n|) \\ &\quad + V(t)\sum_1^N n|n\rangle\langle n|,\end{aligned}\quad (1)$$

where  $N$  is the number of lattice sites,  $|n\rangle$  is the state localized at the  $n$ th site and the  $\Omega_n$ 's are couplings between adjacent sites.  $V(t) = \mathcal{E}(t)d$  is periodic with period  $T = 2\pi/\omega$ .  $V(t)$  arises from the interaction with an external electric field  $\mathcal{E}(t)$ ,  $d$  being the well spacing.

The Hamiltonian (1) could describe an electron in a multiple quantum-well structure, or an ion in an optical lattice. For neutral atoms in an optical lattice analogous Hamiltonian is realized by phase-modulating the optical waves creating the lattice [8]. Equation (1) can also be used to represent the dynamics of circular Rydberg atomic states in a circularly polarized microwave field (the so-called Trojan states) [10], or the Zeeman effect in crossed magnetic fields. The coalescence of Zeeman lines in an oscillating magnetic field crossed with a constant magnetic field, observed almost 30 years ago [11], is formally equivalent [9] to the suppression of tunneling discovered in 1990s. We also note recent control experiments [12], where the time-dependent magnetic field was actively controlled to create a prescribed coherent superposition of Zeeman levels.

To explore the dynamics of the system described by Eq. (1), we first apply a unitary transformation  $|\Psi(t)\rangle$

$=\hat{U}(t)|\Psi'(t)\rangle$ , where  $\hat{U}(t)\equiv\exp[-if_0^t V(t')dt'\hat{N}]$  and  $\hat{N}\equiv\sum n|n\rangle\langle n|$ . This is a direct analog of the Kramers-Henneberger transformation often used for studying atoms in strong high-frequency fields [13]: it gives the exact solution of the problem when  $H_0=0$ . The transformed Hamiltonian is

$$\hat{H}'=\sum_1^{N-1}\Omega_n(G(t)|n\rangle\langle n+1|+G^*(t)|n+1\rangle\langle n|), \quad (2)$$

where  $G(t)\equiv\exp[-if^t V(t')dt']$ . For a periodic  $V(t)$ ,  $G(t)=\sum_{k=-\infty}^{\infty}G_k\exp(-ik\omega t)$ . If  $V(t)$  includes a slowly varying envelope  $f(t)$ , such as we shall introduce later, to turn on the laser field, then  $G_k$  is replaced by  $f(t)G_k$ . The population of the  $n$ th well is  $P_n\equiv|\langle n|\Psi(t)\rangle|^2=|\langle n|\Psi'(t)\rangle|^2$ .

The Hamiltonian  $\hat{H}'$  describes  $N$  degenerate energy levels coupled by a multicolor ‘‘field’’  $G(t)$ . Its time-independent part  $G_0$  provides a resonant coupling, and dominates over the high-frequency, off-resonance couplings,  $G_k\exp(-ik\omega t)$ , which primarily cause energy shifts similar to ac Stark shifts. Following the usual procedure for ac Stark shifts, we eliminate the fast time dependence by treating terms such as  $\Omega_n[G_k\exp(-ik\omega t)|n\rangle\langle n+1|+G_k^*\exp(ik\omega t)|n+1\rangle\langle n|]$  in second-order time-dependent perturbation theory. For example, the term  $G_k^*\exp(ik\omega t)|n+1\rangle\langle n|$  gives an amplitude  $\langle n+1|\Psi'(t)\rangle=-\langle n|\Psi'\rangle\Omega_n G_k^*\exp(ik\omega t)/k\omega$  in the state  $|n+1\rangle$  which, when substituted back into  $i\langle n|\Psi'(t)\rangle$ , yields  $-\langle n|\Psi'(t)\rangle\Omega_n^2 G_k G_k^*/k\omega$ . This diagonal contribution describes the energy shift.

When all the shifts are accounted for to second order we obtain the following time-independent effective Hamiltonian:

$$\begin{aligned} \hat{H}'_{eff} &= \sum_1^{N-1}\Omega_n[G_0|n\rangle\langle n+1|+G_0^*|n+1\rangle\langle n|] \\ &+ G_{\Sigma}\sum_1^N(\Omega_{n-1}^2-\Omega_n^2)|n\rangle\langle n|, \end{aligned} \quad (3)$$

where  $G_{\Sigma}=\sum_{k\neq 0}G_k G_k^*/k\omega$ ,  $\Omega_0\equiv\Omega_N\equiv 0$ , and the result holds if  $\omega\gg|G_k\Omega_n|$  for all  $n$ .

Of the same order as the ac Stark shifts are the ‘‘two-photon’’ Raman-type couplings between the degenerate states  $|n\rangle$  and  $|n+2\rangle$  due to  $G(t)=\sum G_k\exp(-ik\omega t)$ . These terms are absent from Eq. (3) because the corresponding matrix elements that enter to second order,  $\Omega_{n,n+2}^{(2)}=\Omega_n\Omega_{n+1}\sum_{k\neq 0}G_k G_{-k}/k\omega$ , vanish, as can be seen by changing the summation index from  $k$  to  $-k$ .

The stationary eigenstates  $|\Psi'\rangle$  of  $H'_{eff}$  are approximations to the Floquet states of  $\hat{H}'$  and, hence, of  $\hat{H}$  (up to the phase-altering transformation  $\hat{U}$ ). The dominant part of the rapid time dependence of  $|\Psi\rangle=\hat{U}(t)|\Psi'\rangle$  (with the period of the driving field) is included in  $\hat{U}(t)$ . The relatively slow time dependence of  $|\Psi'\rangle$ , due, for instance, to the turning on or off of the laser field, is included in  $H'_{eff}$  by replacing  $G_k$  with  $f(t)G_k$ . We now discuss the rich physics contained in  $H'_{eff}$  and illustrate the effects with numerical examples.

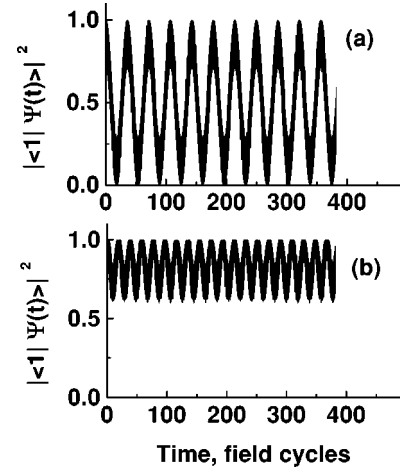


FIG. 1. One-frequency vs two-frequency localization for  $N=2$  wells. Curves show population in the state  $|n=1\rangle$ . Initially  $|\Psi(t=0)\rangle=|1\rangle$ ; the field turn-on is instantaneous. (a) Single frequency,  $V_0/\omega=2.525$ ,  $\Omega/\omega=1/4$ . (b) Two frequencies,  $V_0/\omega=2.60$ ,  $\Omega/\omega=1/4$ ,  $\phi=0$ .

Equation (3) shows that the oscillating field  $V(t)$  induces energy shifts  $\Delta_n$  in the diagonal terms that are proportional to differences in the coupling strengths,  $\Delta_n=G_{\Sigma}(\Omega_{n-1}^2-\Omega_n^2)$ , breaking the degeneracy of the site energies. The distribution of shifts among the lattice sites is determined by  $\Omega_n$ 's, but the overall magnitude and sign are controlled by the magnitude and sign of  $G_{\Sigma}$ , which are determined by  $V(t)$ . Furthermore,  $V(t)$  modifies the couplings between the sites:  $\Omega_n\rightarrow\Omega_n G_0$ .

When  $V(t)$  is such that  $G_0$  is zero,  $H'_{eff}$  is diagonal, with eigenvalues, or quasienergies,  $\tilde{E}_n=G_{\Sigma}(\Omega_{n-1}^2-\Omega_n^2)$  and eigenstates  $|n\rangle$ . The Floquet states of the dressed system become localized on lattice sites. Thus, coherent decoupling of lattice sites, or coherent destruction of tunneling between them, has been achieved.

For the case of a single-frequency field  $V(t)=V_0\cos\omega t$ , the condition  $G_0=0$  for the coherent decoupling of lattice sites reduces to the well-known result [6]  $J_0(V_0/\omega)=0$ , where  $J_0$  is the zero-order Bessel function. However, for a single-frequency field  $G_{\Sigma}=0$ , since  $|G_k|=|G_{-k}|$ . Consequently there are no diagonal energy shifts; the on-site energies remain degenerate. Tunneling is destroyed only at  $G_0=J_0(V_0/\omega)=0$ , and recovers as soon as  $G_0$  deviates from zero, requiring exact tuning of  $V_0/\omega$ .

In contrast, the addition of the second frequency,  $V(t)=V_0[\cos(\omega t)+\cos(2\omega t+\phi)]$ , ensures that  $|G_k|\neq|G_{-k}|$  and so  $G_{\Sigma}\neq 0$  (except at  $\phi=\pm\pi/2$ ). This lifts the degeneracy of the site energies, creating energy defects in the lattice and making localization of the Floquet states robust. Localization persists as long as the energy shifts are large enough:  $\Omega_n|G_0|<|G_{\Sigma}(\Omega_{n+1}^2-\Omega_n^2)|$ .

This qualitative difference between the effects of single-frequency and two-frequency fields is illustrated in Fig. 1. The Schrödinger equation given by  $\hat{H}$  in Eq. (1) was integrated numerically to obtain the populations of the sites as functions of time. The results shown in Fig. 1 are for a double-well system with  $\phi=0$ . In a monochromatic field [Fig. 1(a)], a small 5% detuning of  $V_0$  from the value at

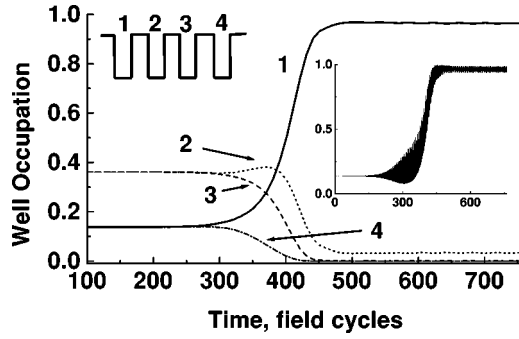


FIG. 2. Adiabatic localization in an  $N=4$ -well system (sketched in the upper left corner). Curves show occupation in  $|n\rangle$ 's well, as numbered. Initially  $|\Psi(t=0)\rangle$  is in the delocalized ground state of  $\hat{H}_0$ . All  $\Omega_n$  are equal,  $\Omega_n=\Omega$ ;  $V_0/\omega=2.48$ ,  $\Omega/\omega=1/4$ ,  $\phi=0$ . For each point on the  $n$ th curve the occupations are averaged over ten cycles. Inset shows full time dependence for  $|n=1\rangle$  before averaging, demonstrating the extent of fast oscillations in the occupation of the first well.

which  $G_0=0$  [given by  $J_0(V_0/\omega)=0$ ] destroys the localization completely: all population moves back and forth between the two wells. In the two-frequency field [Fig. 1(b)] the same 5% detuning of  $V_0$  from the condition  $G_0=0$  does not destroy the effect; localization is robust with respect to small changes in the field.

For nondegenerate Floquet states the system, starting in an eigenstate of  $H_0$ , evolves adiabatically into a single Floquet state of  $H$  as the laser field  $V(t)$  is slowly turned on. According to Eq. (3), the two-frequency field breaks the degeneracy of the Floquet states, and thus adiabatic localization of an electron around the induced defects is possible. Figure 2 shows numerical results for a four-well system with  $\Omega_n$  the same for all  $n$ .  $V_0$  is chosen so that  $G_0=0$ , making  $H'_{eff}$  diagonal. The initial state is the delocalized ground state of  $H_0$ . As the field  $V(t)=V_0[\cos(\omega t)+\cos(2\omega t+\phi)]$  is slowly turned on, Fig. 2 shows that the population is adiabatically localized in the leftmost (first) well for  $\phi=0$ . Localization occurs in the rightmost (fourth) well for  $\phi=\pi$  (not shown).

Adiabatic localization can be achieved at sites for which the eigenstates of  $H'_{eff}$  are nondegenerate. Inspection of Eq. (3) shows that under the conditions used for Fig. 2, where all  $\Omega_n$  are equal (and  $G_0=0$ ), the eigenstates of  $H'_{eff}$  are degenerate, except for the leftmost well with an energy shifted down by  $G_\Sigma\Omega$ , and the rightmost well shifted up by  $G_\Sigma\Omega$ . These are the only wells where robust localization is possible for equal  $\Omega_n$ . As the field is slowly turned on, the ground state of  $H_0$  evolves into the lowest-energy Floquet state of  $H$ , which corresponds to the leftmost well when  $G_\Sigma>0$ . Changing the relative phase  $\phi$  of the two frequencies from 0 to  $\pi$  reverses the sign of  $G_\Sigma$  and moves the lowest-energy Floquet state to the rightmost well.

If the set of  $\Omega_n$ 's values is chosen suitably, localization can be engineered in any selected well. The spectrum of site energies in  $H'_{eff}$  is determined by (i) the  $n$  dependence  $\Omega_n^2$ , and (ii) the sign of  $G_\Sigma$ , which is reversed by changing  $\phi$  from  $\phi=0$  to  $\phi=\pi$ . For example, with  $\Omega_n^2\propto(n-N/2)^2$  the second term in the Hamiltonian equation (3) depends linearly on  $n$ , as if there were a dc bias across the lattice. Changing the relative phase from  $\phi=0$  to  $\phi=\pi$  reverses the sign of

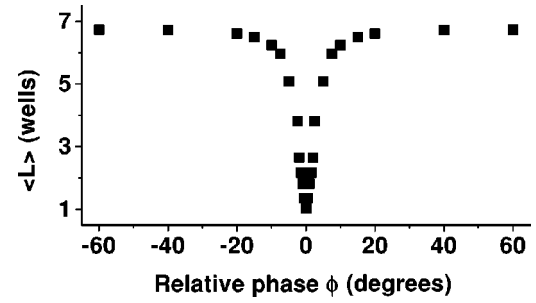


FIG. 3. Phase control of the Floquet states' localization length in an ( $N=10$ )-well system with random couplings:  $\Omega_n=0.5(1+\alpha)\Omega$ ;  $\alpha$  is random between 0 and 1.  $V_0/\omega=2.48$ ;  $\Omega/\omega=1/4$ .

$G_\Sigma$  and, hence, the sign of the dc bias induced by the periodic field.

Our next example (Fig. 3) shows phase control of the localization length of the Floquet states and, hence, of quantum transport properties in a lattice with random couplings  $\Omega_n$ . Figure 3 was calculated for  $N=10$  wells with  $\Omega_n=0.5(1+\alpha)\Omega$  and  $\alpha$  random between 0 and 1. The localization length  $L$  of a state  $|\psi_j\rangle$  is defined as  $L_j=1/\sum_n|\langle n|\psi_j\rangle|^4$ , which gives  $L=N$  for equal populations in each well. In Figure 3 we show the localization length averaged over all  $N=10$  Floquet states (found numerically). For each of them  $|\langle n|\psi_j\rangle|^2$  is averaged over the field period. Bare states are strongly delocalized, with average localization length  $\langle|L|\rangle=6.74$ . In contrast, when the energy shifts induced by the applied field exceed the field-modified couplings between the wells,  $\Omega_n|G_0|$ , the Floquet states localize on single sites for  $\phi=0, \pm\pi$ . Changing  $\phi$  controls  $\langle|L|\rangle$  (Fig. 3).

One of many physical situations described by the tight-binding Hamiltonian in Eq. (1) is the Zeeman effect for a system with fixed total angular momentum  $J$ , such as an atom in a given electronic state, in crossed magnetic fields. We take the constant field  $B_x$  to be along the  $x$  axis, the oscillating field  $B_z(t)$  to be along the  $z$  axis, and the states  $|n\rangle$  to be the eigenstates of  $\hat{J}_z$ , with  $n$  ranging from  $-J$  to  $J$  and  $N=2J+1$ . Consequently,  $\hat{H}_0=g\mu_B B_x \hat{J}_x$ , and  $V(t)=g\mu_B B_z(t)$ , where  $\mu_B$  is the Bohr magneton and  $g$  is the Landé factor. The couplings,  $\Omega_n=g\mu_B B_x \langle n|\hat{J}_x|n+1\rangle$ , vary with  $n$ .

Following the method outlined above, the transformation  $\hat{U}(t)=\exp[-i\hat{J}_z g\mu_B \int_0^t B_z(t') dt']$  is a time-dependent rotation. The new frame rotates back and forth about the  $z$  axis through an angle  $\theta=g\mu_B \int B_z(t') dt'$ .  $J_z$  is unaffected by this rotation. The transformed and effective Hamiltonians are

$$\hat{H}' = \frac{g\mu_B B_x}{2} [G(t)\hat{J}_- + G^*(t)\hat{J}_+], \quad (4)$$

$$\hat{H}'_{eff} = \frac{g\mu_B B_x}{2} (G_0\hat{J}_- + G_0^*\hat{J}_+) + G_\Sigma \frac{(g\mu_B B_x)^2}{2} \hat{J}_z,$$

$$G(t) = \exp\left(-ig\mu_B \int_0^t B_z(t') dt'\right),$$



where  $\hat{J}_{\pm} \equiv \hat{J}_x \pm i\hat{J}_y$ . In  $H'_{eff}$  the term proportional to  $\hat{J}_z$  arises from the difference in couplings,  $\langle n|\hat{J}_x|n+1\rangle$ . The term  $G_0\hat{J}_- + G_0^*\hat{J}_+$  in  $H'_{eff}$  reduces to  $2|G_0|\hat{J}_x$  after an additional rotation about the  $z$  axis by a constant angle  $\theta_0$  defined through  $G_0 = |G_0|\exp(-i\theta_0)$ . This rotation is made in the direction opposite to the previous one, and again, does not affect  $J_z$ . The resulting effective Hamiltonian takes a simple form  $A\hat{J}_x + C\hat{J}_z$ , with  $A = g\mu_B B_x G_0$  and  $C = G_{\Sigma}(g\mu_B B_x)^2/2$ .

When  $B_z(t) = 0, G_{\Sigma} = 0$ ; thus  $C = 0$  and the eigenstates of the system have well-defined  $J_x$ . However, when the amplitude of  $B_z(t)$  is such that  $G_0 = 0$ ,  $A$  vanishes and  $J_z$  becomes a good quantum number, as reported [11] for a single-color case. In the two-color case  $J_z$  remains a good quantum number as long as the effective field along the  $x$  axis,  $B_x^{(eff)} = |G_0|B_x$ , is sufficiently small:  $|G_0|g\mu_B B_x \ll G_{\Sigma}(g\mu_B B_x)^2$ .

As with the lattice, we can adiabatically move the system from an initial eigenstate of  $J_x$  to an eigenstate of  $J_z$  by slowly turning on a suitably chosen  $B_z(t)$ . Since the expect-

ation value  $\langle J_z \rangle$  is invariant under rotations about the  $z$  axis, and we control  $\langle J_z \rangle$  in the rotating frame through the two-color field, we control  $\langle J_z \rangle$  in the laboratory frame. For example, changing  $\phi$  reverses the direction of  $\langle J_z \rangle$ .

So far we have neglected the effect of decoherence, which is important in quantum semiconductor structures. The key parameter should be the ratio of the field period  $T$  to the phase relaxation time  $T_{ph}$ . For  $T \ll T_{ph}$  there is sufficient time to establish the Floquet states, and the relaxation will occur between these rather than the bare states [6,14]. If the magnitude of field-induced energy shifts,  $\Delta_n$  exceeds the energy relaxation width  $T_{en}^{-1}$ , localization survives. In the opposite case of  $\Delta_n T_{en} < 1$  an interesting situation arises if  $\Omega_n$  are chosen to ensure that  $\Delta_n$  depends linearly on  $n$ . Then, as we have seen, the two-color field introduces an effective dc bias that will induce a tunneling current. Its direction is reversed by changing the relative phase of the two frequencies  $\phi$  from 0 to  $\pi$ . This complements phase control of ionization current first demonstrated in [4].

- 
- [1] See, e.g., H. Stapefeldt *et al.*, Phys. Rev. Lett. **79**, 2787 (1997); T. Takekoshi, B.M. Patterson, and R.J. Knize, *ibid.* **81**, 5105 (1998); A. N. Nikolov *et al.* (unpublished); T. Seideman, J. Chem. Phys. **106**, 2881 (1997); H. Sakai *et al.*, Phys. Rev. A **57**, 2794 (1998); B. Friedrich and D. Herschbach, Phys. Rev. Lett. **74**, 4623 (1995).
- [2] See, e.g., R. J. Gordon and S. A. Rice, Ann. Rev. Phys. Chem. **48**, 601 (1997); M. Shapiro and P. Brumer, J. Chem. Soc., Faraday Trans. **93**, 1263 (1997); H. Rabitz, Adv. Chem. Phys. **101**, 315 (1997).
- [3] T. Weinacht, J. Ahn, and P.H. Bucksbaum, Nature (London) **397**, 233 (1999).
- [4] E. Dupont *et al.*, Phys. Rev. Lett. **74**, 3596 (1995).
- [5] See, e.g., *Coherent Control in Atoms, Molecules, and Semiconductors*, edited by W. Pötz and A. Schroeder (Kluwer, Dordrecht, 1999).
- [6] See review by M. Grifoni and P. Haenggi, Phys. Rep. **304**, 229 (1998).
- [7] B.J. Keay *et al.*, Phys. Rev. Lett. **75**, 4102 (1995).
- [8] K.W. Madison *et al.*, Phys. Rev. Lett. **81**, 5093 (1998).
- [9] M. Holthaus, in *Coherent Control in Atoms, Molecules, and Semiconductors* (Ref. [5]), p. 171.
- [10] See, e.g., M. Kalinski and J. H. Eberly, Opt. Express **1**, 215 (1997), and references therein; I. Bialynicki-Birula, M. Kalinski, and J.H. Eberly, Phys. Rev. Lett. **73**, 1777 (1994); A.F. Brunello, T. Uzer, and D. Farrelly, *ibid.* **76**, 2874 (1996).
- [11] S. Haroche *et al.*, Phys. Rev. Lett. **24**, 861 (1970).
- [12] D. J. Heinzen and G. Xu (unpublished); see also G. Xu and D. Heinzen, Phys. Rev. A **59**, R922 (1999) for one-color experiments.
- [13] See, e.g., N. B. Delone and V. P. Krainov, *Multiphoton Processes in Atoms* (Springer-Verlag, Berlin, 1994).
- [14] O. Kocharovskaya, P. Mandel, and M.O. Scully, Phys. Rev. Lett. **74**, 2451 (1995).